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September 2014

FOD8383
2.5 A Output Current, High-Speed, MOSFET/IGBT Gate Drive Optocoupler in Optoplanar® Wide-Body SOP 5-Pin

Features

- Reliable and High-Voltage Insulation with Greater than 10 mm Creepage and Clearance Distance and 0.5 mm Internal Insulation Distance
- 2.5 A Output Current Driving Capability for Medium-Power IGBT/MOSFET
  - P-Channel MOSFET at Output Stage Enables Output Voltage Swing Close to Supply Rail
- 35 kV/µs Minimum Common Mode Rejection
- Wide Supply Voltage Range: 15 V to 30 V
- Fast Switching Speed Over Full Operating Temperature Range
  - 210 ns Maximum Propagation Delay
  - 65 ns Maximum Pulse-Width Distortion
- Under-Voltage Lockout (UVLO) with Hysteresis
- Extended Industrial Temperate Range: -40°C to 100°C
- Safety and Regulatory Approvals:
  - UL1577, 5,000 VAC_{RMS} for 1 Minute
  - DIN-EN/IEC60747-5-5, 1,414 V Peak Working Insulation Voltage

Applications

- AC and Brushless DC Motor Drives
- Industrial Inverter
- Uninterruptible Power Supply
- Induction Heating
- Isolated IGBT/Power MOSFET Gate Drive

Related Resources

- *FOD3184—3 A Output Current, High-Speed MOSFET/IGBT Gate Drive Optocoupler Datasheet*
- *www.fairchildsemi.com/products/opto/*

Description

The FOD8383 is a 2.5 A output current gate drive optocoupler capable of driving medium-power IGBT/MOSFETs. It is ideally suited for fast-switching driving of power IGBT and MOSFET used in motor-control inverter applications and high-performance power systems.

The FOD8383 utilizes Fairchild's Optoplanar® coplanar packaging technology and optimized IC design to achieve reliable high-insulation voltage and high-noise immunity.

It consists of an Aluminum Gallium Arsenide (AlGaAs) Light-Emitting Diode (LED) optically coupled to an integrated circuit with a high-speed driver for push-pull MOSFET output stage. The device is housed in a wide body, 5-pin, small-outline, plastic package.

Functional Schematic

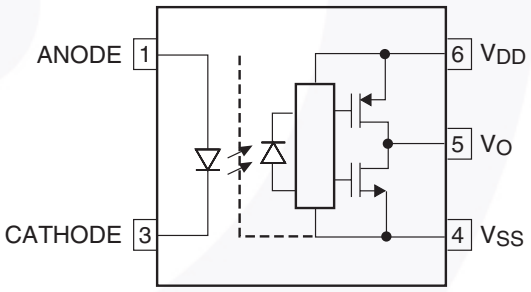

Figure 1. Schematic

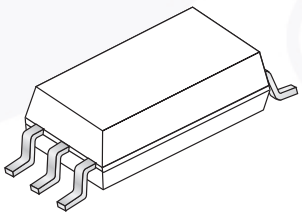

Figure 2. Package Outline

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Truth Table

LED	$V_{DD} - V_{SS}$ "Positive Going" (Turn-on)	V_{DD}–V_{SS} "Positive Going" (Turn-off)	V_O
Off	0 V to 30 V	0 V to 30 V	LOW
On	0 V to 11.5 V	0 V to 10 V	LOW
On	11.5 V to 14.5 V	10 V to 13 V	Transition
On	14.5 V to 30 V	13 V to 30 V	HIGH

Pin Configuration

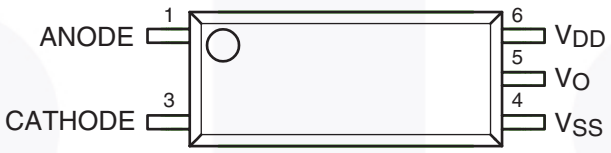

Figure 3. Pin Configuration

Pin Definitions

Pin #	Name	Description
1	Anode	LED Anode
3	Cathode	LED Cathode
4	V_{SS}	Negative Supply Voltage
5	V_O	Output Voltage
6	V_{DD}	Positive Supply Voltage

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Safety and Insulation Ratings

As per DIN EN/IEC60747-5-5, this optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter	Min.	Typ.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				
	For Rated Mains Voltage < 150 V_{RMS}		I–IV		
	For Rated Mains Voltage < 300 V_{RMS}		I–IV		
	For Rated Mains Voltage < 450 V_{RMS}		I–IIII		
	For Rated Mains Voltage < 600 V_{RMS}		I–III		
	Climatic Classification		40/100/21		
	Pollution Degree (DIN VDE 0110/1.89)		2		
CTI	Comparative Tracking Index	175			
V_{PR}	Input-to-Output Test Voltage, Method b, V_{IORM} x 1.875 = V_{PR}, 100% Production Test with t_m = 1 s, Partial Discharge < 5 pC	2651			V_{peak}
	Input-to-Output Test Voltage, Method a, V_{IORM} x 1.6 = V_{PR}, Type and Sample Test with t_m = 10 s, Partial Discharge < 5 pC	2262			V_{peak}
V_{IORM}	Maximum Working Insulation Voltage	1414			V_{peak}
V_{IOTM}	Highest Allowable Over Voltage	8000			V_{peak}
	External Creepage	10.0			mm
	External Clearance	10.0			mm
	Insulation Thickness	0.5			mm
	Safety Limit Values – Maximum Values Allowed in the Event of a Failure				
T_S	Case Temperature	150			°C
$I_{S,INPUT}$	Input Current	200			mA
$P_{S,OUTPUT}$	Output Power	600			mW
R_{IO}	Insulation Resistance at T_S, V_{IO} = 500 V	10^9			Ω

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. T_A = 25ºC unless otherwise specified.

Symbol	Parameter	Value	Units
T_{STG}	Storage Temperature	-40 to +125	°C
T_{OPR}	Operating Temperature	-40 to +100	°C
T_J	Junction Temperature	-40 to +125	°C
T_{SOL}	Lead Solder Temperature *Refer to Reflow Temperature Profile on page 15.*	260 for 10 s	°C
$I_{F(AVG)}$	Average Input Current	25	mA
V_R	Reverse Input Voltage	5.0	V
$I_{O(PEAK)}$	Peak Output Current(1)	3.0	A
$V_{DD} – V_{SS}$	Supply Voltage	-0.5 to 35	V
$V_{O(PEAK)}$	Peak Output Voltage	0 to V_{DD}	V
PD_I	Input Power Dissipation(2)(4)	45	mW
PD_O	Output Power Dissipation(3)(4)	500	mW

Notes:

1. Maximum pulse width = 10 µs, maximum duty cycle = 0.2%.
2. No derating required across operating temperature range.
3. Derate linearly from 25°C at a rate of 5.2 mW/°C.
4. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
T_A	Ambient Operating Temperature	-40	100	°C
$V_{DD} – V_{SS}$	Supply Voltage	15	30	V
$I_{F(ON)}$	Input Current (ON)	10	16	mA
$V_{F(OFF)}$	Input Voltage (OFF)	0	0.8	V

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Isolation Characteristics

Apply over all recommended conditions; typical value is measured at T_A = 25ºC.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	T_A = 25ºC, R.H. < 50%, t = 60 s, $I_{I-O} \leq$ 20 µA, 50 Hz(5)(6)	5,000			V_{RMS}
R_{ISO}	Isolation Resistance	V_{I-O} = 500 V(5)		10^{11}		Ω
C_{ISO}	Isolation Capacitance	V_{I-O} = 0 V, Frequency = 1.0 MHz(6)		1		pF

Notes:

5. Device is considered a two-terminal device: pins 1 and 3 are shorted together and pins 4, 5 and 6 are shorted together.
6. 5,000 VAC_{RMS} for 1 minute duration is equivalent to 6,000 VAC_{RMS} for 1 second duration.

Electrical Characteristics

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units	Figure
V_F	Input Forward Voltage	I_F = 10 mA	1.10	1.43	1.80	V	19
$\Delta(V_F / T_A)$	Temperature Coefficient of Forward Voltage			-1.5		mV/°C	
BV_R	Input Reverse Breakdown Voltage	I_R = 10 µA	5			V	
C_{IN}	Input Capacitance	f = 1 MHz, V_F = 0 V		60		pF	
I_{OH}	High Level Output Current(1)	$V_{OH} = V_{DD}$ – 1 V		-0.9	-0.5	A	4, 6
		$V_{OH} = V_{DD}$ – 6 V			-2.5	A	4, 6, 22
I_{OL}	Low Level Output Current(1)	$V_{OL} = V_{SS}$ + 1 V	0.5	1.0		A	7, 9
		$V_{OL} = V_{SS}$+ 6 V	2.5			A	7, 9, 21
V_{OH}	High Level Output Voltage(7)(8)	I_F = 10 mA, I_O = -2.5 A	V_{DD} – 7.0			V	4
		I_F = 10 mA, I_O = -100 mA	V_{DD} – 0.5			V	4, 5, 23
V_{OL}	Low Level Output Voltage(7)(8)	I_F = 0 mA, I_O = 2.5 A			V_{SS} + 7.0	V	7
		I_F = 0 mA, I_O = 100 mA			V_{SS} + 0.5	V	8, 24
I_{DDH}	High Level Supply Current	V_O = Open, I_F = 7 to 16 mA		2.9	3.5	mA	10, 11, 25
I_{DDL}	Low Level Supply Current	V_O = Open, V_F = 0 to 0.8 V		2.8	3.5	mA	10, 11, 26
I_{FLH}	Threshold Input Current Low-to-High	I_O = 0 mA, V_O > 5 V		3.1	7.5	mA	12, 18, 27
V_{FHL}	Threshold Input Voltage High-to-Low	I_O = 0 mA, V_O < 5 V	0.8			V	28
V_{UVLO+}	Under-Voltage Lockout Threshold	I_F = 10 mA, V_O > 5 V	11.5	13.0	14.5	V	20, 29
V_{UVLO-}		I_F = 10 mA, V_O < 5 V	10.0	11.5	13.0	V	20, 29
$UVLO_{HYS}$	Under-Voltage Lockout Threshold Hysteresis			1.5		V	

Notes:

7. In this test, V_{OH} is measured with a dc load current of 100 mA. When driving capacitive load V_{OH} will approach V_{DD} as I_{OH} approaches 0 A.
8. Maximum pulse width = 1 ms, maximum duty cycle = 20%.

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Switching Characteristics

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units	Figure
t_{PHL}	Propagation Delay Time to Logic LOW Output(9)	I_F = 7 mA to 16 mA, R_g = 10 Ω, C_g =10 nF, f = 250 kHz, Duty Cycle = 50%	50	145	210	ns	13, 14, 15, 16, 17, 30
t_{PLH}	Propagation Delay Time to Logic HIGH Output(10)		50	135	210	ns	13, 14, 15, 16, 17, 30
PWD	Pulse Width Distortion(11) $\lvert t_{PHL} - t_{PLH} \rvert$			25	65	ns	
PDD (Skew)	Propagation Delay Difference Between Any Two Parts(12)		-90		90		
t_R	Output Rise Time (10% to 90%)			35		ns	30
t_F	Output Fall Time (90% to 10%)			25		ns	30
$t_{ULVO\ ON}$	ULVO Turn-On Delay	I_F = 10 mA, V_O > 5 V		1.7		µs	
$t_{ULVO\ OFF}$	ULVO Turn-Off Delay	I_F = 10 mA, V_O < 5 V		0.1		µs	
$\lvert CM_H \rvert$	Common Mode Transient Immunity at Output HIGH	T_A = 25°C, V_{DD} = 30 V, I_F = 10 to 16 mA, V_{CM} = 1500 V(13)	35	50		kV/µs	31
$\lvert CM_L \rvert$	Common Mode Transient Immunity at Output LOW	T_A = 25°C, V_{DD} = 30 V, V_F = 0 V, V_{CM} = 1500 V(14)	35	50		kV/µs	31

Notes:

9. Propagation delay t_{PHL} is measured from the 50% level on the falling edge of the input pulse to the 50% level of the falling edge of the V_O signal.
10. Propagation delay t_{PLH} is measured from the 50% level on the rising edge of the input pulse to the 50% level of the rising edge of the V_O signal.
11. PWD is defined as $\lvert t_{PHL} - t_{PLH} \rvert$ for any given device.
12. The difference between t_{PHL} and t_{PLH} between any two FOD8383 parts under the same operating conditions, with equal loads.
13. Common mode transient immunity at output high is the maximum tolerable negative dVcm/dt on the trailing edge of the common mode impulse signal, V_{CM}, to ensure that the output remains high (i.e., V_O > 15.0 V).
14. Common mode transient immunity at output low is the maximum tolerable positive dVcm/dt on the leading edge of the common pulse signal, V_{CM}, to ensure that the output remains low (i.e., V_O < 1.0 V).

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Typical Performance Characteristics

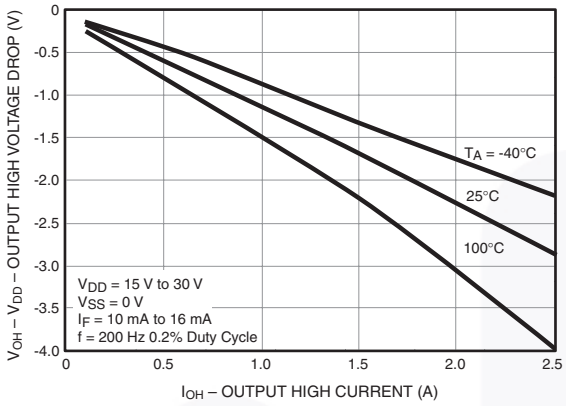

Figure 4. Output High Voltage Drop vs. Output High Current

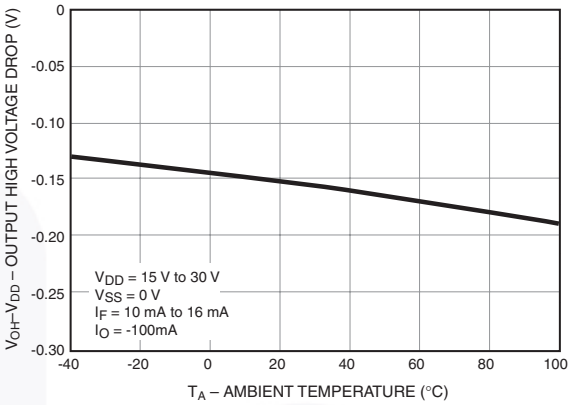

Figure 5. Output High Voltage Drop vs. Ambient Temperature

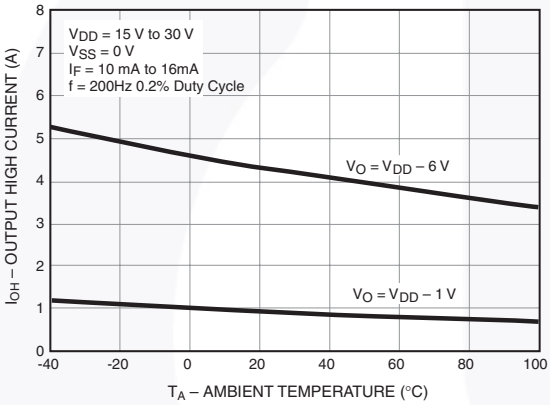

Figure 6. Output High Current vs. Ambient Temperature

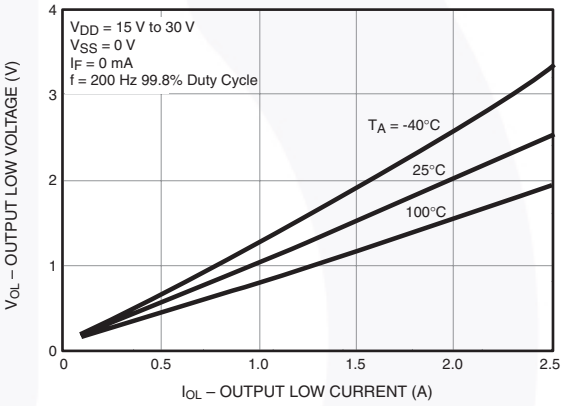

Figure 7. Output Low Voltage vs. Output Low Current

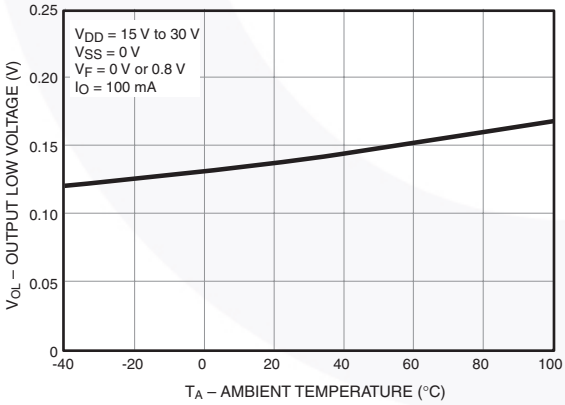

Figure 8. Output Low Voltage vs. Ambient Temperature

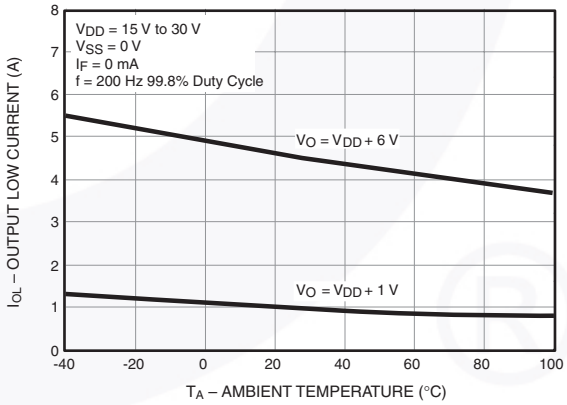

Figure 9. Output Low Current vs. Ambient Temperature

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Typical Performance Characteristics (Continued)

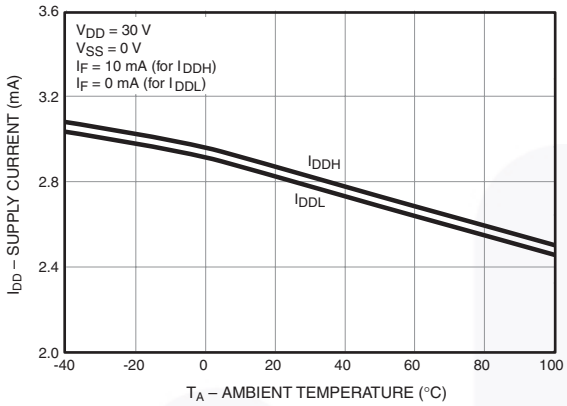

Figure 10. Supply Current vs. Ambient Temperature

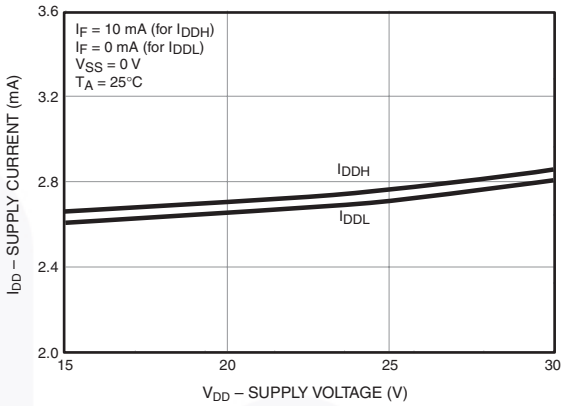

Figure 11. Supply Current vs. Supply Voltage

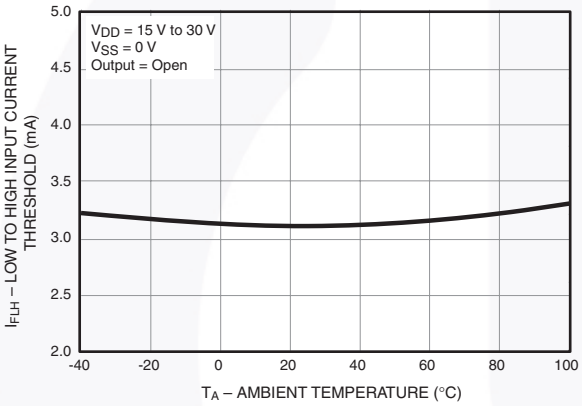

Figure 12. Low-to-High Input Current Threshold vs. Ambient Temperature

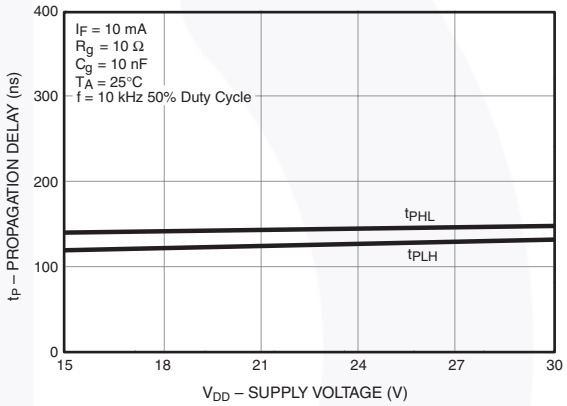

Figure 13. Propagation Delay vs. Supply Voltage

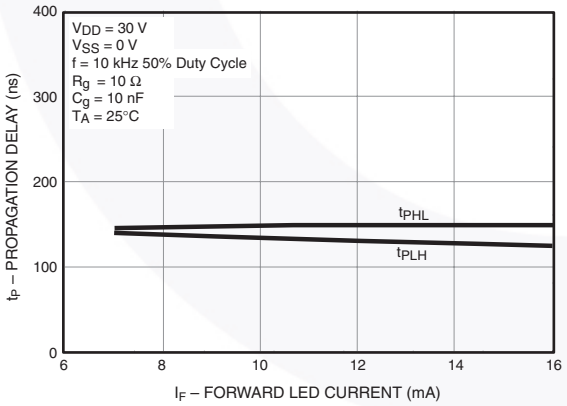

Figure 14. Propagation Delay vs. LED Forward Current

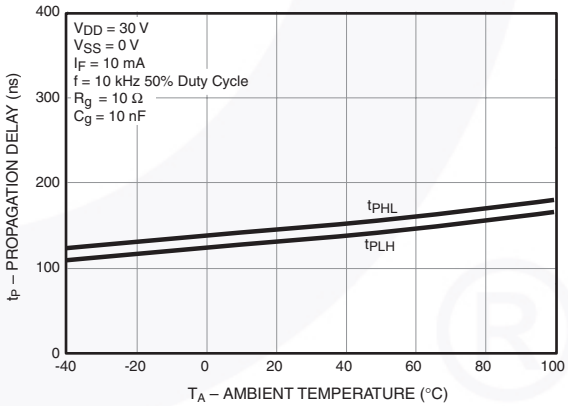

Figure 15. Propagation Delay vs. Ambient Temperature

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Typical Performance Characteristics (Continued)

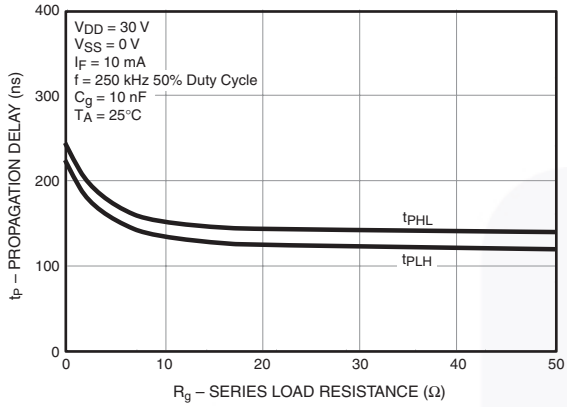

Figure 16. Propagation Delay vs. Series Load Resistance

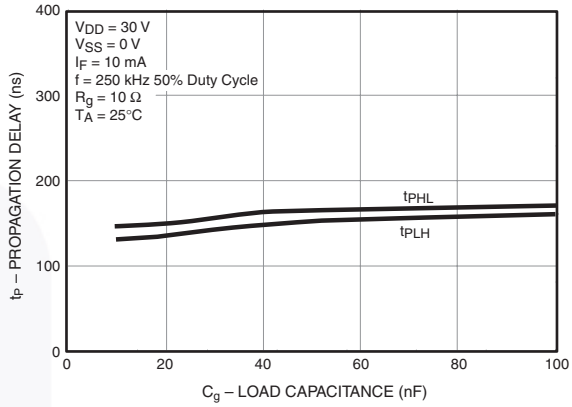

Figure 17. Propagation Delay vs. Load Capacitance

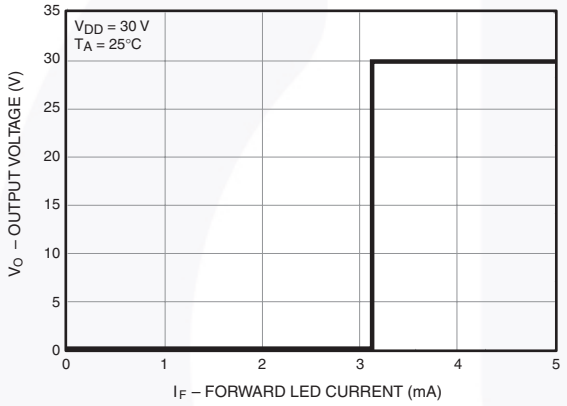

Figure 18. Transfer Characteristics

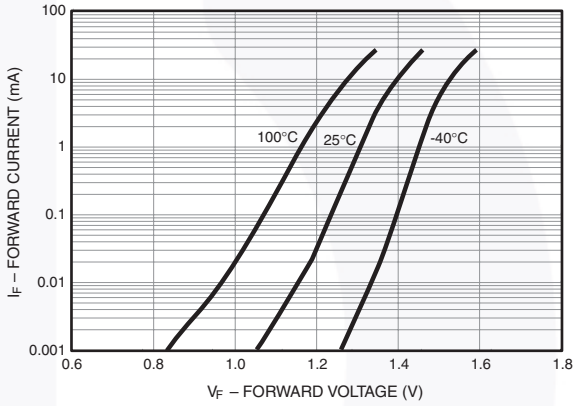

Figure 19. Input Forward Current vs. Forward Voltage

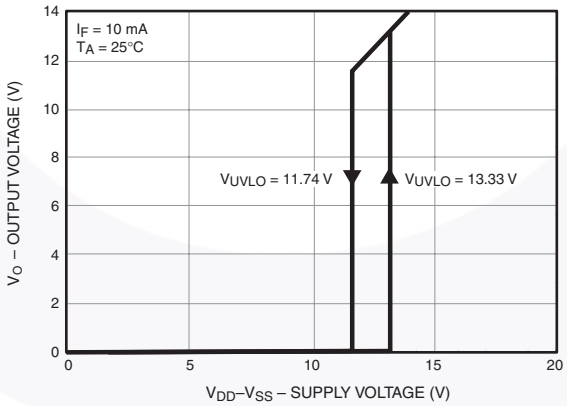

Figure 20. Under-Voltage Lockout

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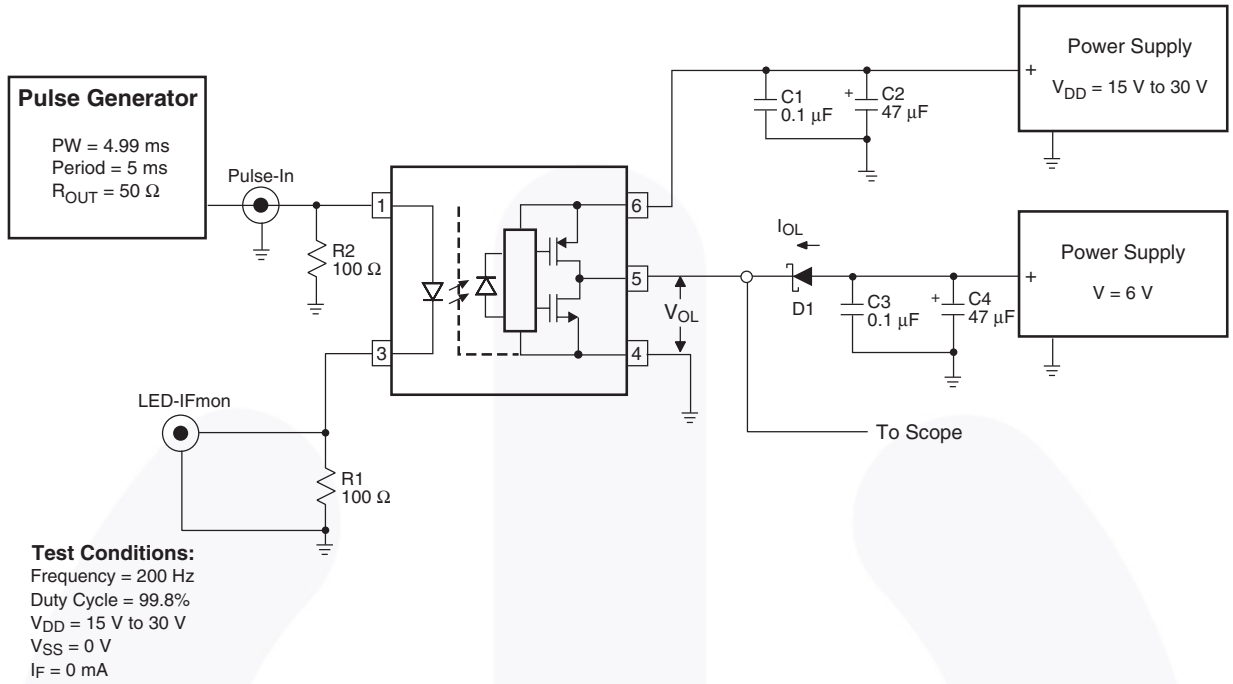
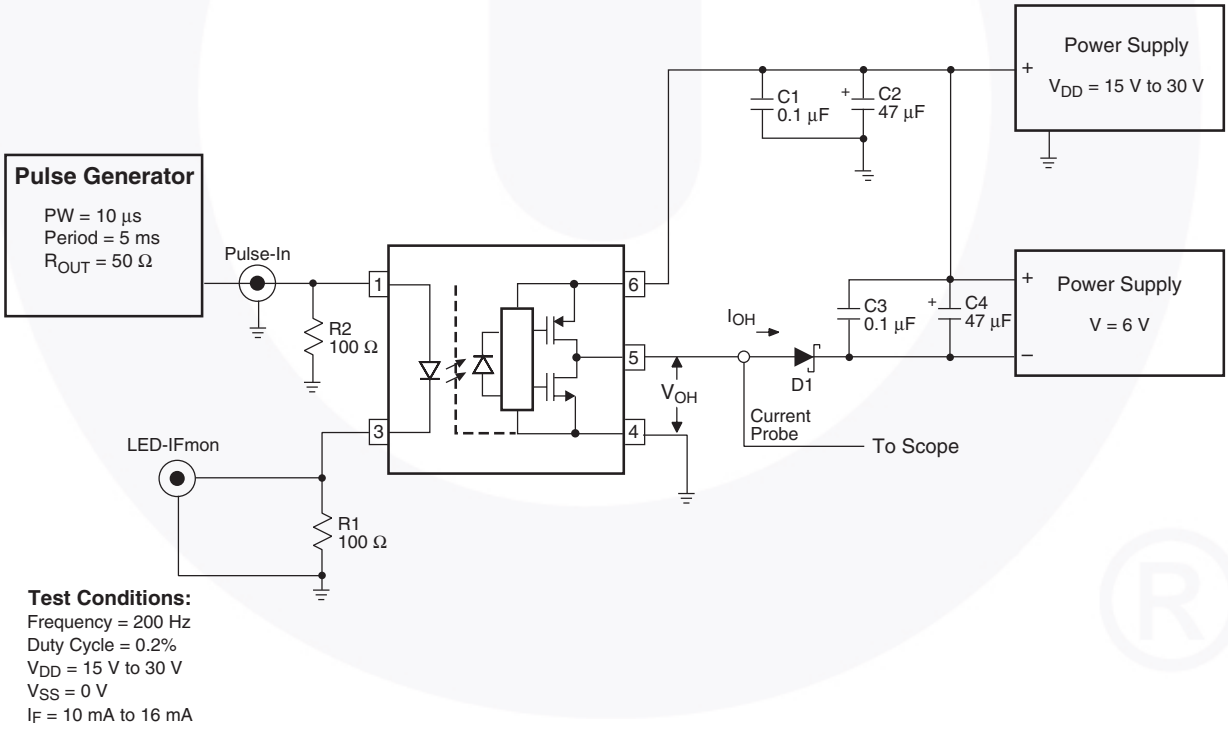
Test Circuit



Test Conditions:
Frequency = 200 Hz
Duty Cycle = 99.8%
V_{DD} = 15 V to 30 V
V_{SS} = 0 V
I_F = 0 mA

Figure 21. I_{OL} Test Circuit



Test Conditions:
Frequency = 200 Hz
Duty Cycle = 0.2%
V_{DD} = 15 V to 30 V
V_{SS} = 0 V
I_F = 10 mA to 16 mA

Figure 22. I_{OH} Test Circuit

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Test Circuit (Continued)

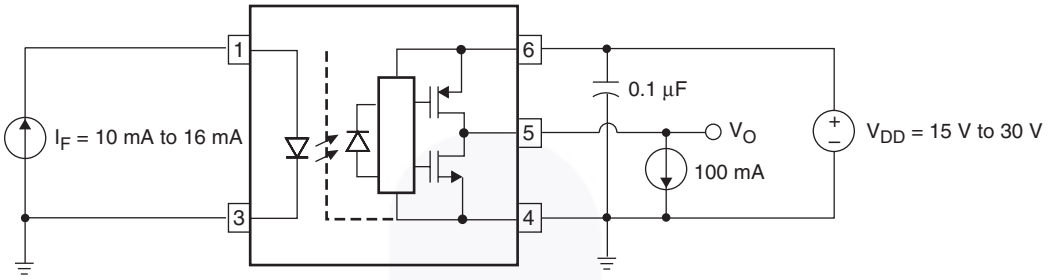

Figure 23. V_{OH} Test Circuit

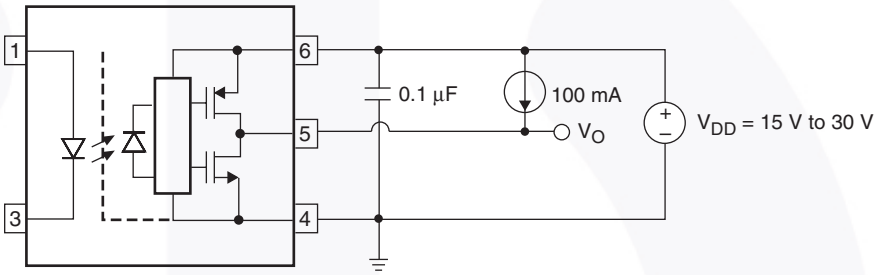

Figure 24. V_{OL} Test Circuit

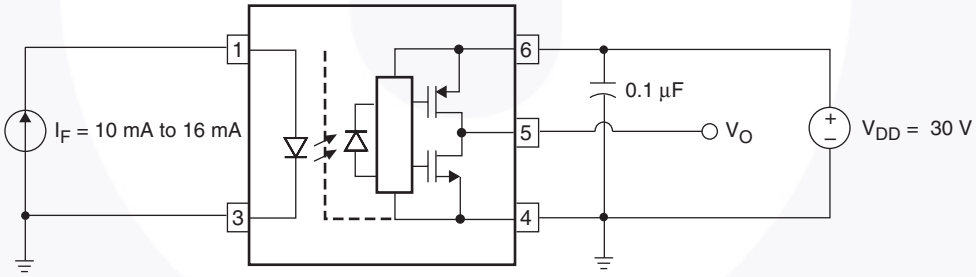

Figure 25. I_{DDH} Test Circuit

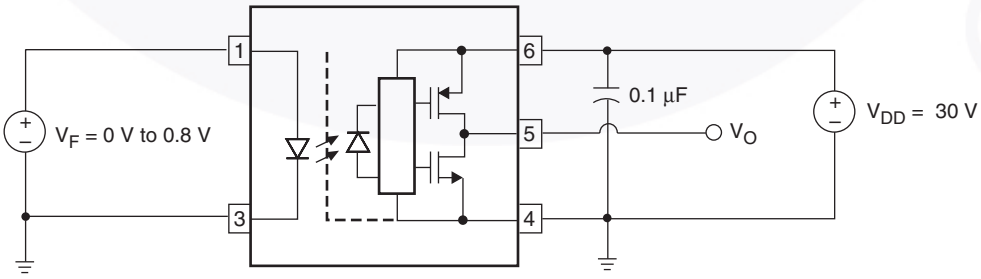

Figure 26. I_{DDL} Test Circuit

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Test Circuit (Continued)

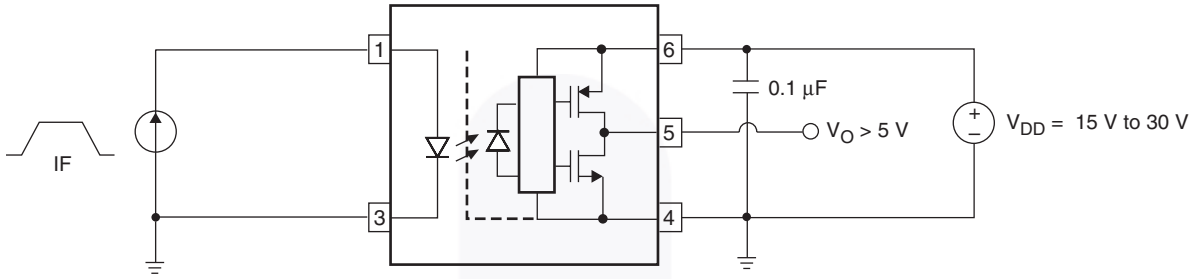

Figure 27. I_{FLH} Test Circuit

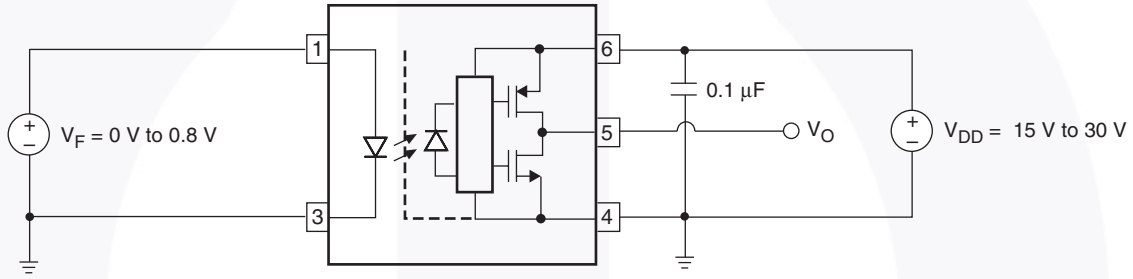

Figure 28. V_{FHL} Test Circuit

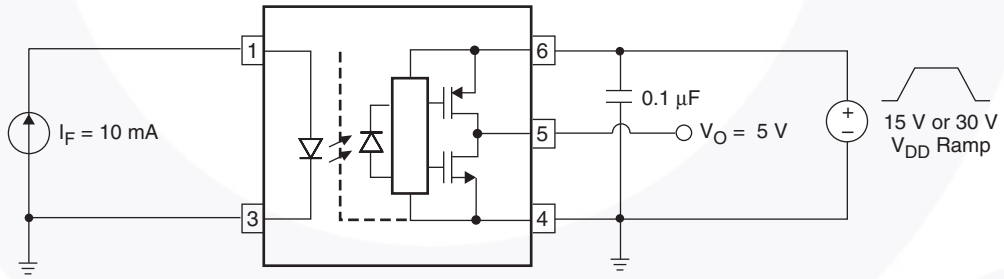

Figure 29. UVLO Test Circuit

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Test Circuit (Continued)

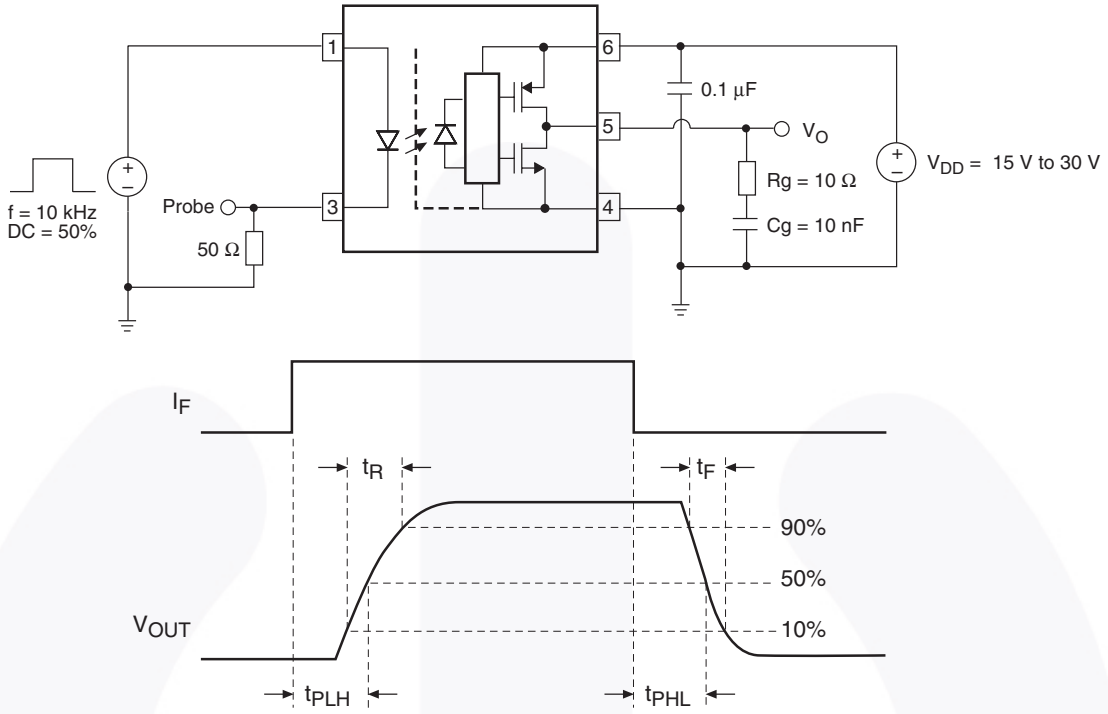

Figure 30. t_{PHL}, t_{PLH}, t_R, and t_F Test Circuit and Waveforms

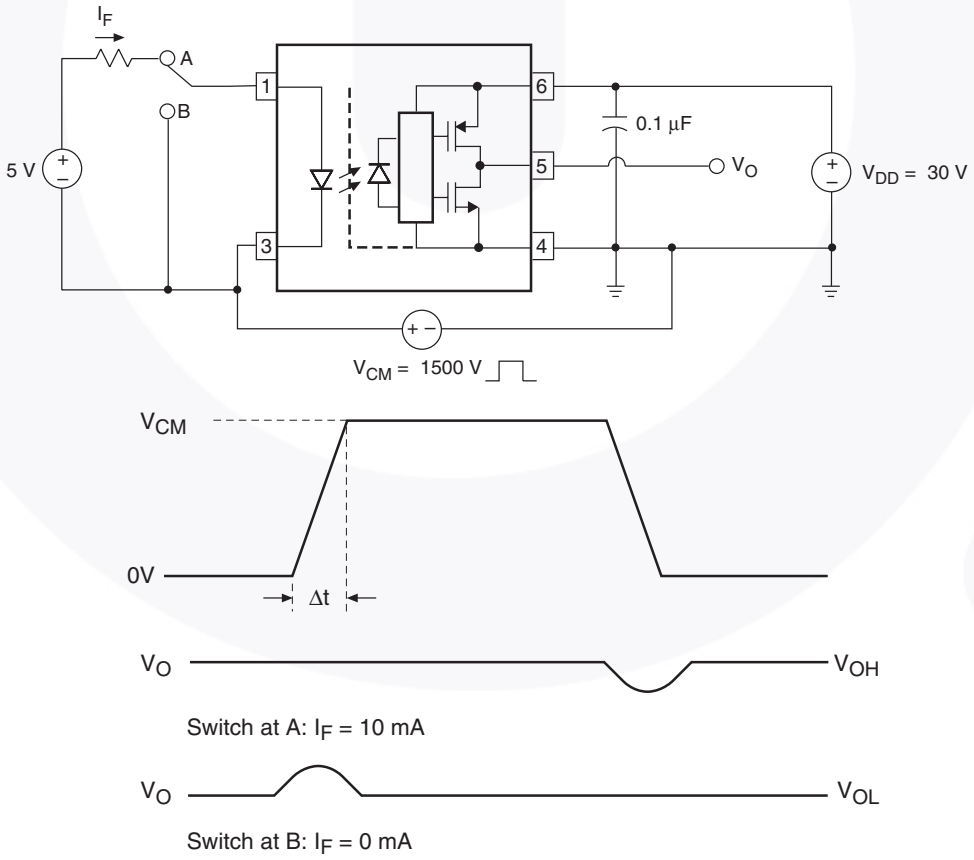

Figure 31. CMR Test Circuit and Waveforms

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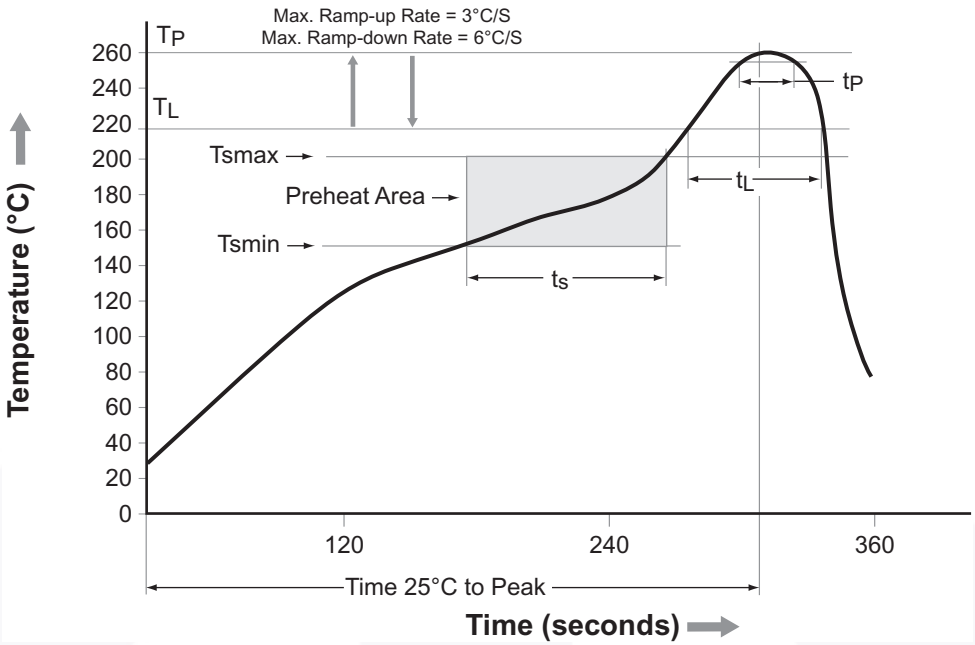
Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Minimum (T_{smin})	150°C
Temperature Maximum (T_{smax})	200°C
Time (t_S) from (T_{smin} to T_{smax})	60 s to 120 s
Ramp-up Rate (t_L to t_P)	3°C/second maximum
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60 s to 150 s
Peak Body Package Temperature	260°C +0°C / –5°C
Time (t_P) within 5°C of 260°C	30 s
Ramp-Down Rate (T_P to T_L)	6°C/s maximum
Time 25°C to Peak Temperature	8 minutes maximum

Figure 32. Reflow Profile

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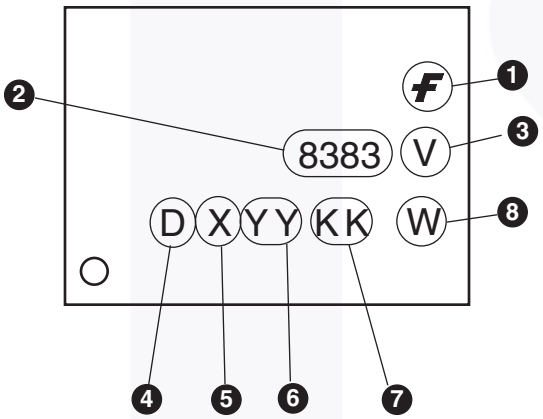
Ordering Information

Part Number	Package	Packing Method
FOD8383	Wide Body SOP 5-Pin	Tube (100 units per tube)
FOD8383R2	Wide Body SOP 5-Pin	Tape and Reel (1,000 units per reel)
FOD8383V	Wide Body SOP 5-Pin, DIN EN/IEC60747-5-5 Option	Tube (100 units per tube)
FOD8383R2V	Wide Body SOP 5-Pin, DIN EN/ IEC60747-5-5 Option	Tape and Reel (1,000 units per reel)

All packages are lead free per JEDEC: J-STD-020B standard.

Marking Information



Definitions	
1	Fairchild logo
2	Device number, e.g., '8383' for FOD8383
3	DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
4	Plant code, e.g., 'D'
5	Last digit year code, e.g., 'C' for 2012
6	Two-digit work week ranging from '01' to '53'
7	Lot traceability code
8	Package assembly code, W

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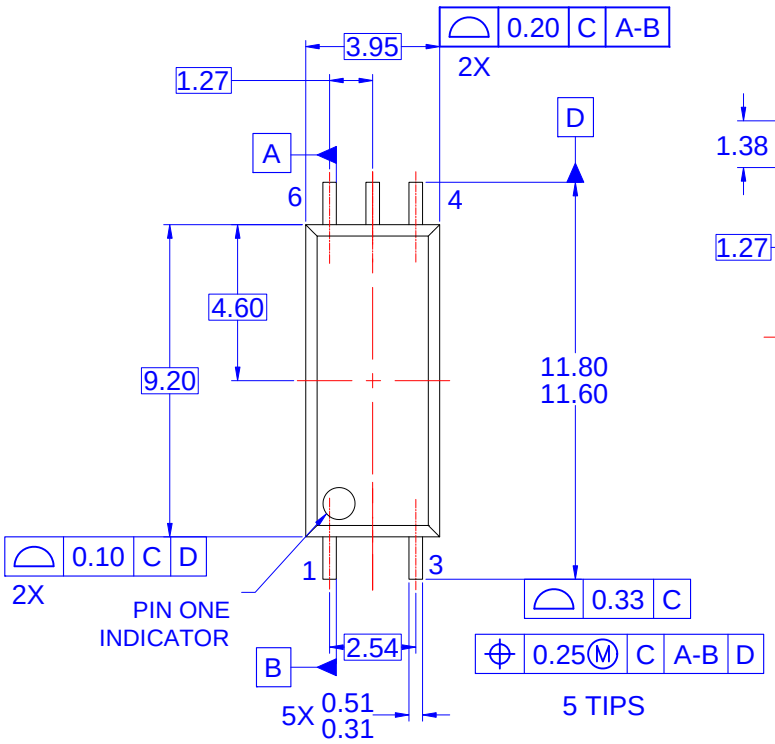
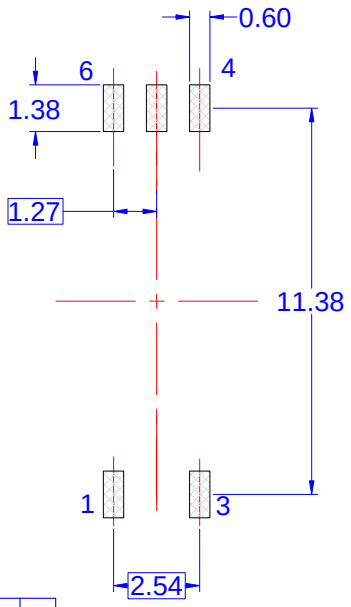
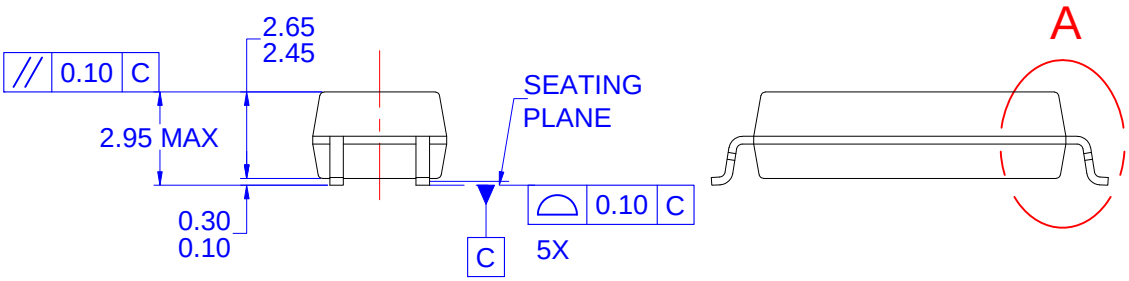
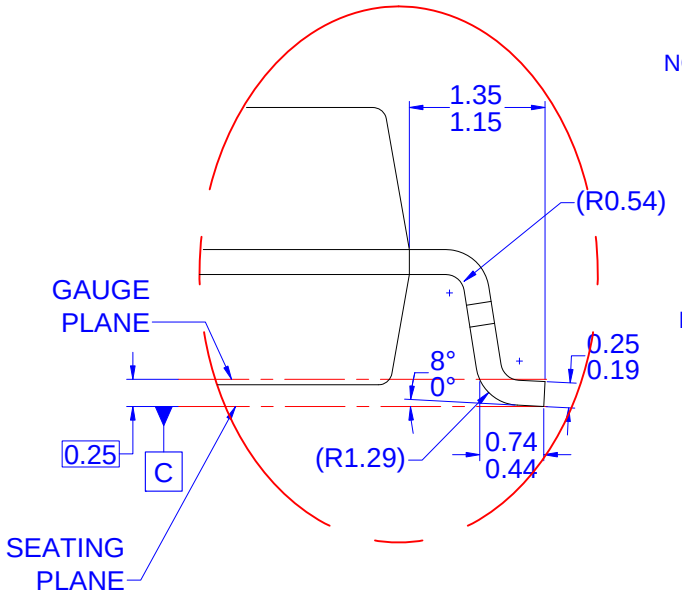




LAND PATTERN
RECOMMENDATION





DETAIL A
SCALE: 3.2:1

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